

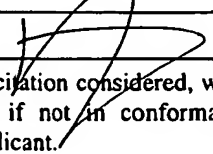


INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary) PTO Form 1449	Atty Docket No. 112857-476	Application No. 10/786,667
	Applicant Biwa et al	
	Filing Date 02/25/04	Group 2812

U.S. PATENT DOCUMENTS						
Examiner's Initials	Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate

FOREIGN PATENT DOCUMENTS							
Examiner's Initials	Document Number	Publication Date	Country	Class	Subclass	Translation	
						Yes	No
MP	WO 98/14986	04-09-98	PCT	_____	_____	_____	_____
MP	10-125929	05-15-98	Japan	_____	_____	_____	_____
MP	2000-332343	11-30-00	Japan	_____	_____	_____	_____
MP	2001-501778	06-02-01	Japan	_____	_____	_____	_____

Examiner's Initials	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)
MP	Kapolnek et al, "Spatial control of InGaN luminescence by MOCVD selective epitaxy", Journal of Crystal Growth 189/190 (1998) pages 83-86.

Examiner: 	Date Considered: 5/05
*Examiner: Initial if citation considered, whether or not citation is in conformance with PEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	